TN06C40SG

Features

N and P-Channel Enhancement Mode Power MOSFET

N-Channel

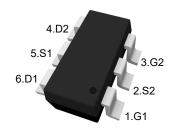
$$\begin{split} V_{DS} &= 40 V, I_{D} = 6.5 A \\ R_{DS(on)} &= 40 m \Omega @V_{GS} = 10 V \\ R_{DS(on)} &= 60 m \Omega @V_{GS} = 4.5 V \end{split}$$

P-Channel

 V_{DS} =-40V, I_{D} =-6A $R_{DS(on)}$ =75m Ω @ V_{GS} =-10V $R_{DS(on)}$ =100m Ω @ V_{GS} =-4.5V

High Power and Current handing capability

SOT-23-6

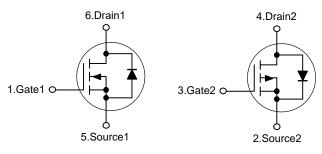


Marking Code:4006

Applications

- Battery protection
- Load switch
- Power management

Schematic Diagram



N-Channel

P-Channel

ABSOLUTE MAXIMUM RATING	is $T_A = \overline{25 ^{\circ}C}$	unless otherwis	e noted		·
Parameter		Symbol	N-Channel	P-Channel	Unit
Drain-Source Voltage		V _{DS}	40	- 40	V
Gate-Source Voltage		V _{GS}	± 20	± 20	
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 25 °C	I _D	6.8	- 6.0	•
	T _A = 70 °C		4.0	- 3.8	
Pulsed Drain Current		I _{DM}	15	- 8	Α
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	3.0	- 2.0	
	T _A = 25 °C	D_	2.15 1.23		W
Maximum Power Dissipation ^{a, b}	T _A = 70 °C	P_{D}			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 5 s	R _{thJA}	93	110	
Maximum Junction-to-Ambient ^a	Steady State	'`thJA	130	150	°C/W
Maximum Junction-to-Lead	Steady State	R _{thJL}	75	90	

Notes:

a. Surface Mounted on FR4 board.

b. $t \le 5$ s.

Parameter	Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
Static					1		1	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	N-Ch	1.0				
		$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	P-Ch	- 1.0			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	N-Ch			± 100	nA	
Cate Body Edukage			P-Ch			± 100		
	I _{DSS}	$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}$	N-Ch			1		
Zero Gate Voltage Drain Current		$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}$	P-Ch			- 1	μA	
Zero Cate voltage Brain Carrent	.033	$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$	N-Ch			5		
		$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$	P-Ch			- 5		
	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	N-Ch	3.7			Λ	
On-State Drain Current ^a		V _{DS} = - 5 V, V _{GS} = - 10 V	P-Ch	- 3			A	
		V _{GS} = 10 V, I _D = 2.5 A	N-Ch		0.030			
		V _{GS} = - 10 V, I _D = - 1.8 A			0.070		_	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 2.0 A	N-Ch		0.035		Ω	
		V _{GS} = - 4.5 V, I _D = - 1.2 A	P-Ch		0.080			
Forward Transconductance ^a	9fs	$V_{DS} = 10 \text{ V}, I_{D} = 2.5 \text{ A}$	N-Ch		4.3			
		V _{DS} = - 15 V, I _D = - 1.8 A	P-Ch		2.4		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 1.05 A, V _{GS} = 0 V	N-Ch		0.81	1.10	V	
		I _S = - 1.05 A, V _{GS} = 0 V	P-Ch		- 0.83	- 1.10		
Dynamic ^b								
Total Gate Charge	0		N-Ch		2.1	3.2		
Total Gate Charge	Q_g	N-Channel V _{DS} = 30V , V _{GS} = 5 V, I _D = 1.8 A	P-Ch		2.4	3.6	nC	
Gate-Source Charge Gate-Drain Charge	Q _{gs}	V _{DS} = 30V, V _{GS} = 3 V, I _D = 1.0 A	N-Ch		0.7			
		P-Channel	P-Ch		0.9			
		$V_{DS} = -30V$, $V_{GS} = -5$ V, $I_{D} = -1.8$ A	N-Ch		0.7			
	- gu		P-Ch		8.0			
Gate Resistance	R_{g}		N-Ch	0.5		2.4	Ω	
	9		P-Ch	3		11	—	
Turn-On Delay Time Rise Time Turn-Off Delay Time	$t_{d(on)}$ t_{r} $t_{d(off)}$	N-Channel	N-Ch		7	11		
		$V_{DD} = 15 \text{ V}, R_L = 15 \Omega$	P-Ch		8	12		
		$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_q = 6 \Omega$	N-Ch P-Ch		9	14		
		-	N-Ch		12 13	18 20	-	
		P-Channel	P-Ch		12	20 18	ns	
Fall Time	t _f	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega$	N-Ch		5	8		
		$I_D \cong -1 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 6 \Omega$	P-Ch		7	11		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.05 A, dI/dt = 100 A/μs	N-Ch		35	60	1	
		I _F = - 1.05 A, dl/dt = 100 A/µs	P-Ch		30	60		

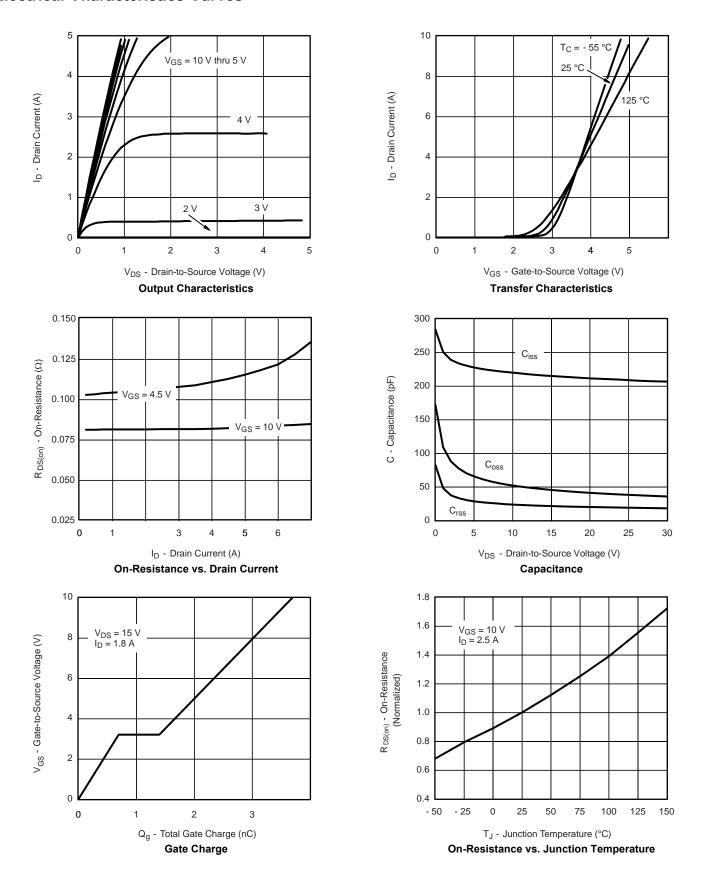
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

N-Channel

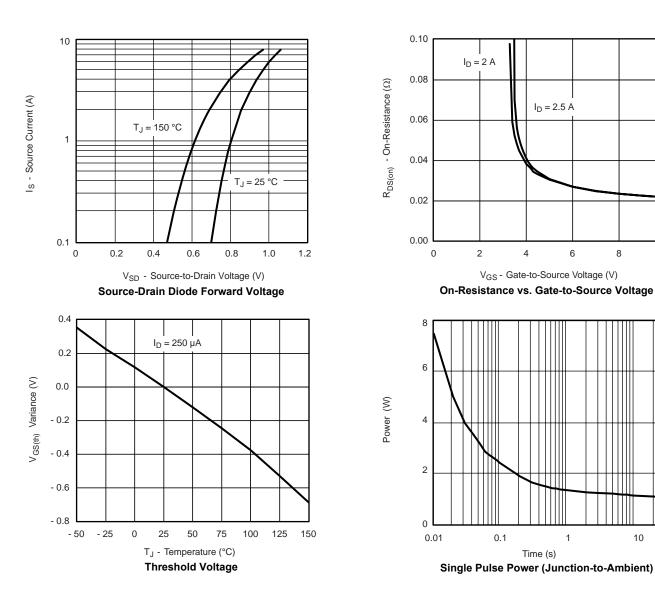
Electrical Characteristics Curves

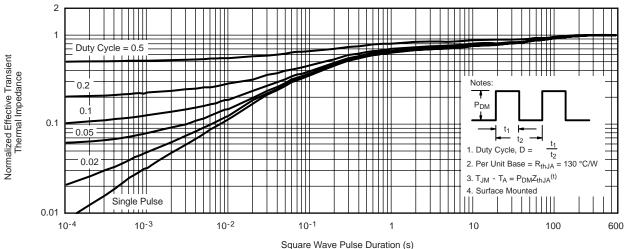


10

30

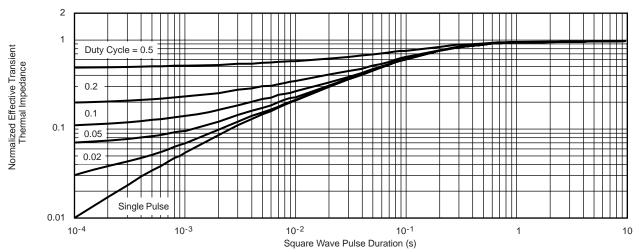
10





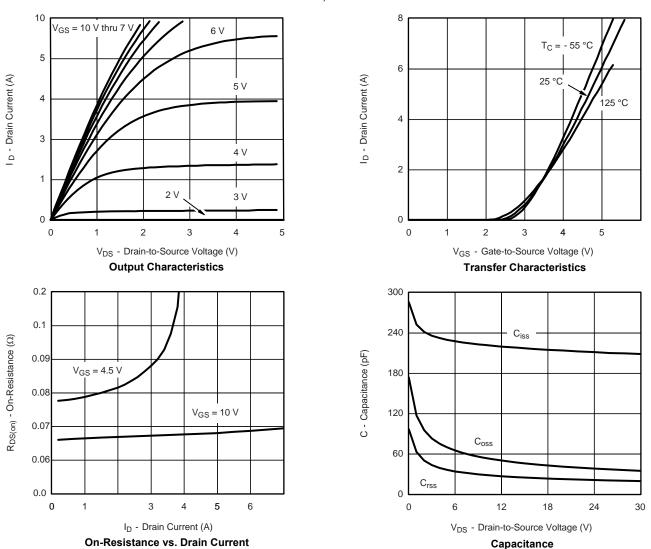
Normalized Thermal Transient Impedance, Junction-to-Ambient

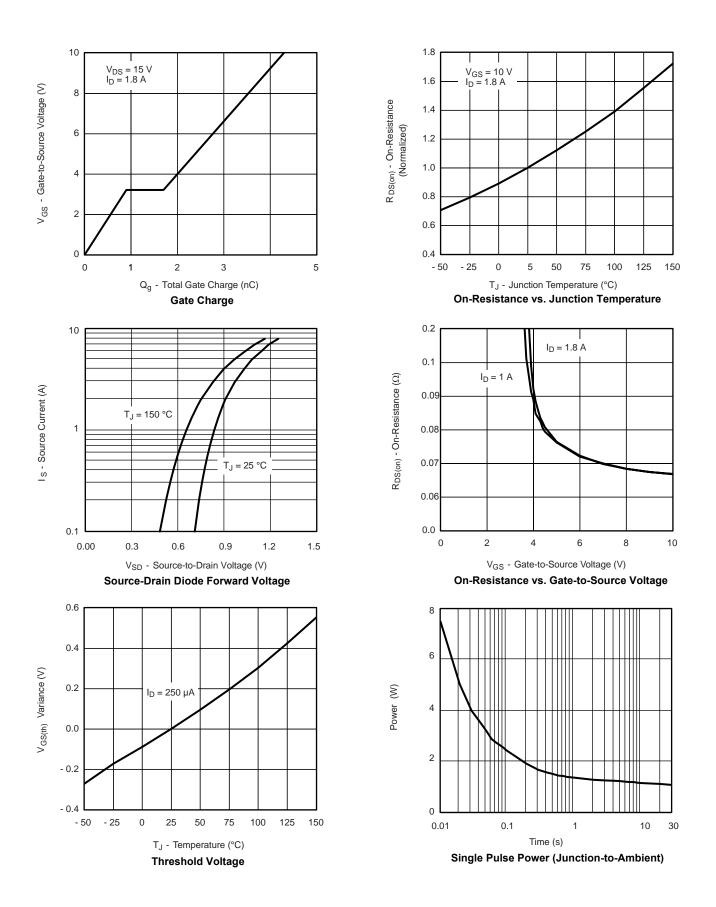
N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



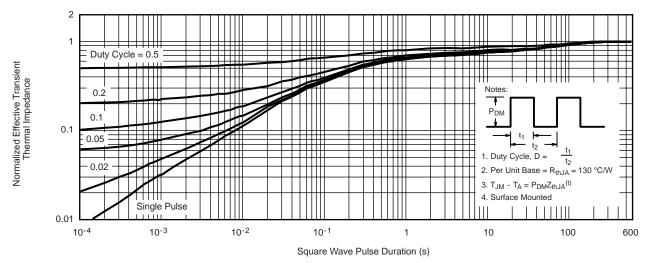
Normalized Thermal Transient Impedance, Junction-to-Foot

P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

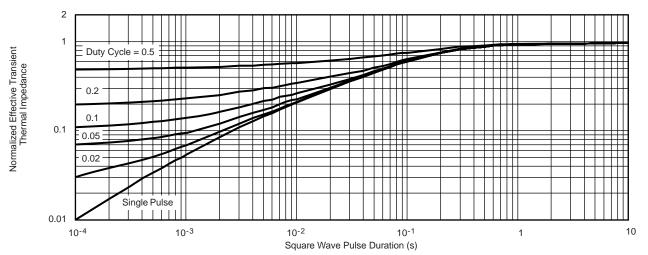




P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

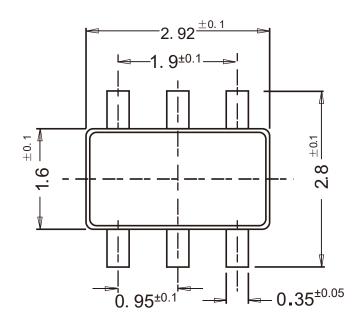


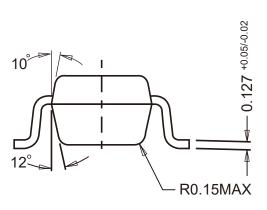
Normalized Thermal Transient Impedance, Junction-to-Foot

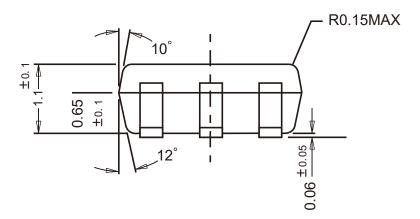
Package Outline

SOT-23-6

Dimensions in mm





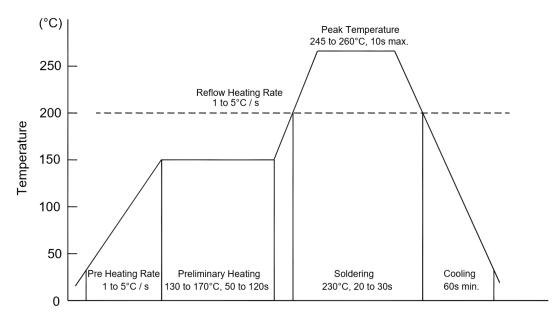


Ordering Information

Device	Package	Shipping		
TN06C40SG	SOT-23-6	3,000PCS/Reel&7inches		

Conditions of Soldering and Storage

Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

Conditions of hand soldering

Temperature: 370 °C

Time: 3s max.Times: one time

♦ Storage conditions

Temperature

5 to 40 °C

Humidity

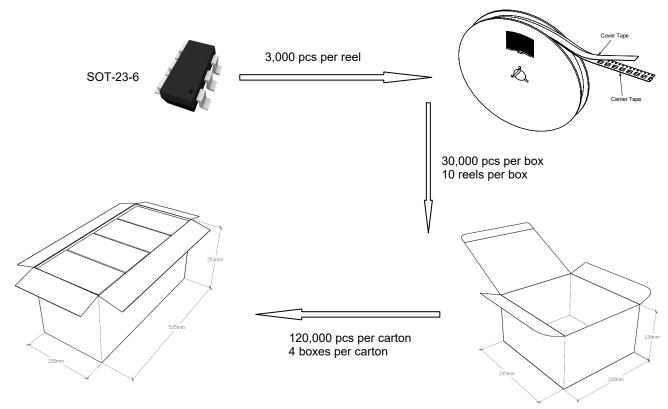
30 to 80% RH

Recommended period

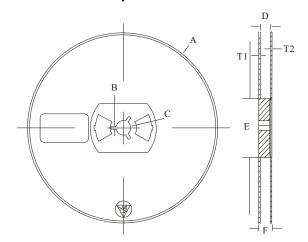
One year after manufacturing

Package Specifications

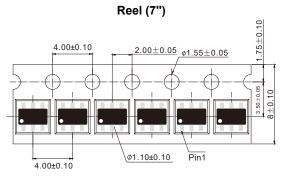
• The method of packaging



♦ Embossed tape and reel data



Symbol	Value (unit: mm)		
Α	Ø 177.8±1		
В	2.7±0.2		
С	Ø 13.5±0.2		
E	Ø 54.5±0.2		
F	12.3±0.3		
D	9.6+2/-0.3		
T1	1.0±0.2		
T2	1.2±0.2		



Tape (8mm)

Contact Information

TANI website: http://www.tanisemi.com Email:tani@tanisemi.com

For additional information, please contact your local Sales Representative.



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Product Specification Statement

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up -to- date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

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Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

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